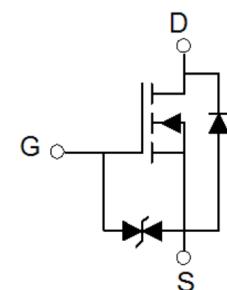
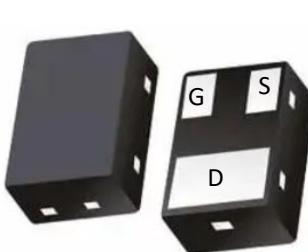


Features

- * $V_{DS} = 30V, I_D = 0.85A$
- * $R_{DS(ON)} = \text{Typ } 350m\Omega @ V_{GS} = 4.5V$
- * $R_{DS(ON)} = \text{Typ } 435m\Omega @ V_{GS} = 2.5V$
- * ESD protected
- * DFN1006-3L package

Package and Circuit diagram



DFN1006-3L

Circuit diagram

Marking Diagram



Ordering Information

| Part Number | Packaging | Reel Size |
|----------------|-------------------|-----------|
| PMZ550UNEYL-CN | 10000/Tape & Reel | 7 inch |

Absolute maximum ratings ($T_A=25^\circ C$ unless otherwise specified)

| Symbol | Parameter | Value | Unit |
|-----------------|---|------------|--------------|
| V_{DS} | Drain-Source Voltage | 30 | V |
| V_{GS} | Gate-Source Voltage | ± 12 | V |
| I_D | Continuous Drain Current ($T_A= 25^\circ C$) | 0.85 | A |
| I_D | Continuous Drain Current ($T_A= 100^\circ C$) | 0.5 | A |
| I_{DM} | Pulsed Drain Current ^{note1} | 2.5 | A |
| P_D | Power Dissipation ($T_A= 25^\circ C$) | 0.2 | W |
| $R_{\theta JA}$ | Thermal Resistance from Junction to Ambient | 625 | $^\circ C/W$ |
| T_J | Maximum Junction Temperature | -55 ~ +150 | $^\circ C$ |
| T_{STG} | Storage Temperature | -55 ~ +150 | $^\circ C$ |

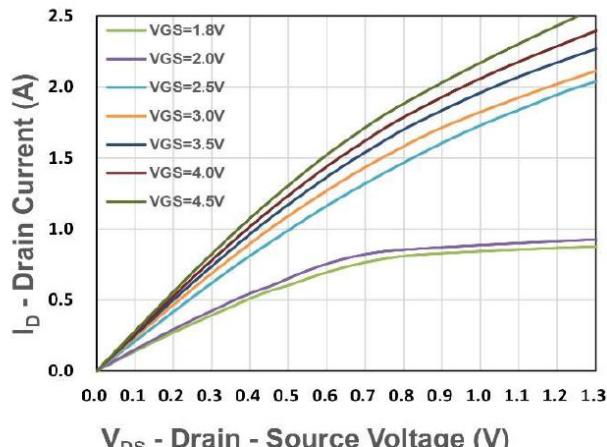
Electrical characteristics ($T_A=25^\circ\text{C}$ unless otherwise specified)

| Symbol | Parameter | Test conditions | Min | Typ | Max | Unit |
|---|--|--|-----|------|----------|------------------|
| Off characteristics | | | | | | |
| $V_{(\text{BR})\text{DS}}$ | Drain-source breakdown voltage | $V_{\text{GS}} = 0\text{V}$, $I_D = 250\mu\text{A}$ | 30 | | | V |
| I_{DS} | Zero gate voltage drain current | $V_{\text{DS}} = 24\text{V}$, $V_{\text{GS}} = 0\text{V}$ | | | 1 | μA |
| I_{GS} | Gate to body leakage current | $V_{\text{DS}} = 0\text{V}$, $V_{\text{GS}} = \pm 12\text{V}$ | | | ± 10 | μA |
| On characteristics | | | | | | |
| $V_{\text{GS}(\text{th})}$ | Gate threshold voltage | $V_{\text{DS}} = V_{\text{GS}}$, $I_D = 250\mu\text{A}$ | 0.6 | 0.95 | 1.3 | V |
| $R_{\text{DS}(\text{on})}$ | Static drain-source on resistance ^{Note2} | $V_{\text{GS}} = 4.5\text{V}$, $I_D = 0.5\text{A}$ | | 350 | 420 | $\text{m}\Omega$ |
| | | $V_{\text{GS}} = 2.5\text{V}$, $I_D = 0.3\text{A}$ | | 435 | 600 | $\text{m}\Omega$ |
| Dynamic characteristics | | | | | | |
| C_{iss} | Input capacitance | $V_{\text{DS}} = 15\text{V}$ $V_{\text{GS}} = 0\text{V}$ $f = 1\text{MHz}$ | | 38.2 | | pF |
| C_{oss} | Output capacitance | | | 4.8 | | pF |
| C_{rss} | Reverse transfer capacitance | | | 3.3 | | pF |
| Q_g | Total gate charge | $V_{\text{DS}} = 15\text{V}$ $I_D = 0.7\text{A}$ $V_{\text{GS}} = 4.5\text{V}$ | | 0.9 | | nC |
| Q_{gs} | Gate-source charge | | | 0.3 | | nC |
| Q_{gd} | Gate-drain charge | | | 0.16 | | nC |
| Switching characteristics | | | | | | |
| $t_{\text{d}(\text{on})}$ | Turn-on delay time | $V_{\text{DS}} = 15\text{V}$ $I_D = 0.7\text{A}$ $R_{\text{GEN}} = 6\Omega$ $V_{\text{GS}} = 4.5\text{V}$ | | 5.4 | | ns |
| t_r | Turn-on rise time | | | 20.2 | | ns |
| $t_{\text{d}(\text{off})}$ | Turn-off delay time | | | 34.4 | | ns |
| t_f | Turn-off fall time | | | 30.3 | | ns |
| Drain-source diode characteristics and maximum ratings | | | | | | |
| V_{SD} | Drain to source diode forward voltage | $V_{\text{GS}} = 0\text{V}$, $I_S = 0.25\text{A}$ | | 0.9 | 1.1 | V |
| I_S | Maximum continuous drain to source diode forward current | | | | 0.85 | A |
| t_{rr} | Body diode reverse recovery time | $I_F = 0.25\text{A}$, $dI/dt = 100\text{A}/\mu\text{s}$ | | 24.2 | | ns |
| Q_{rr} | Body diode reverse recovery charge | | | 3.2 | | nC |

Notes:1. Repetitive rating: pulse width limited by maximum junction temperature

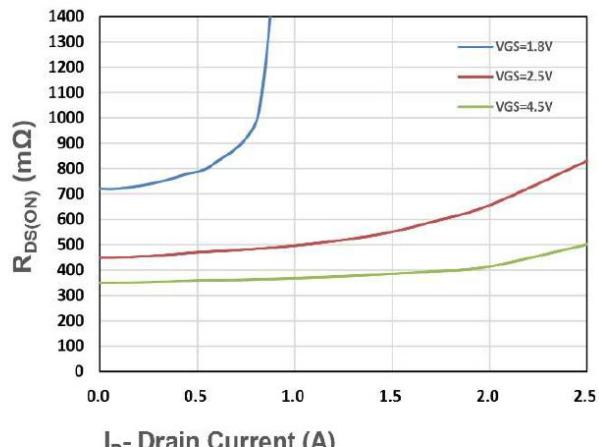
2. Pulse test: pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 0.5\%$

Typical performance characteristics ($T_A=25^\circ\text{C}$ unless otherwise specified)



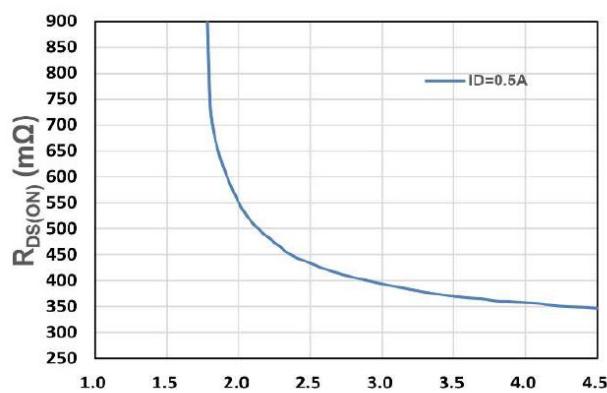
V_{DS} - Drain - Source Voltage (V)

Figure 1. Output Characteristics



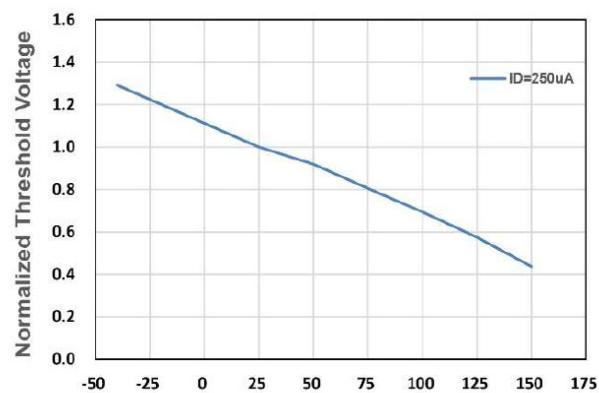
I_D - Drain Current (A)

Figure 2. On-Resistance vs. ID



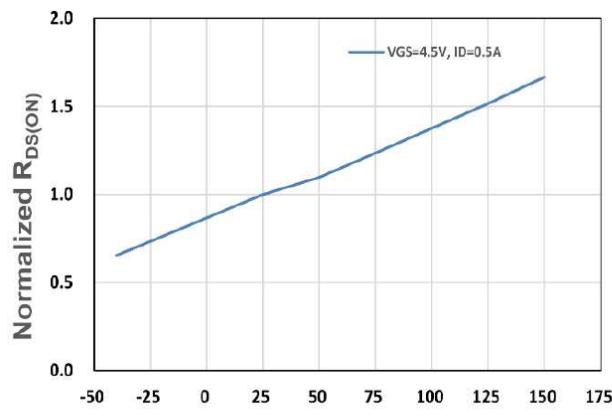
V_{GS} - Gate - Source Voltage (V)

Figure 3. On-Resistance vs. VGS



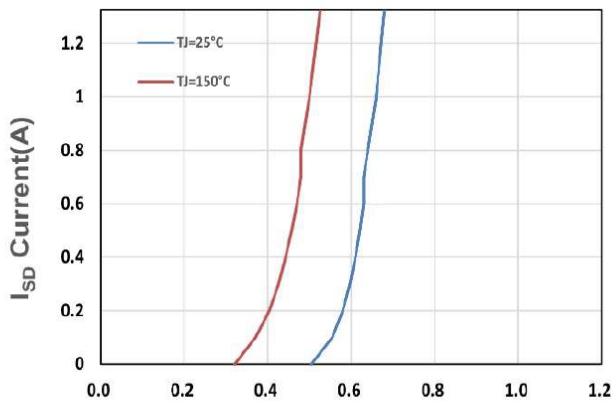
T_j, Junction Temperature(°C)

Figure 4. Gate Threshold Voltage



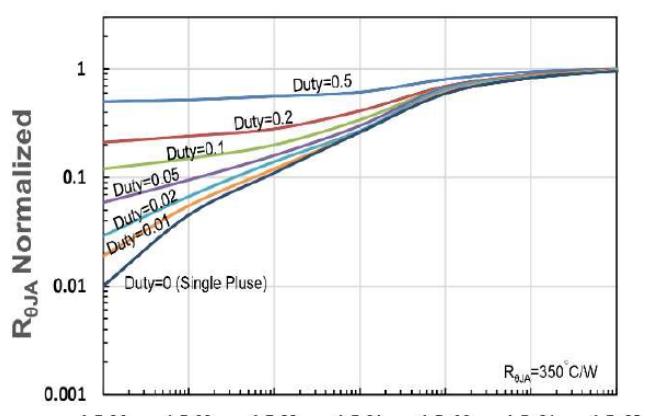
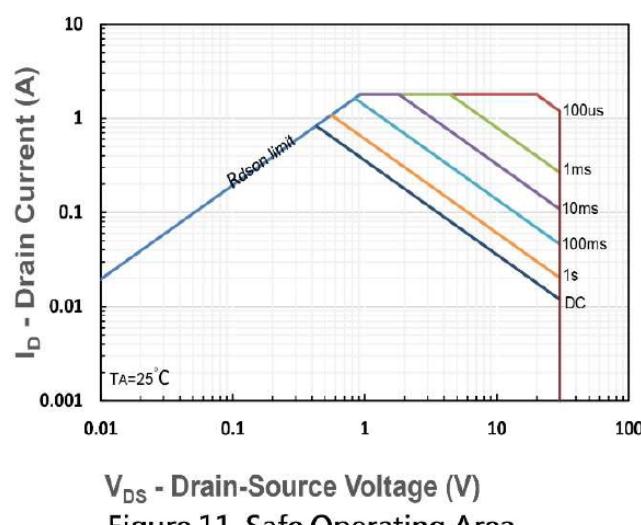
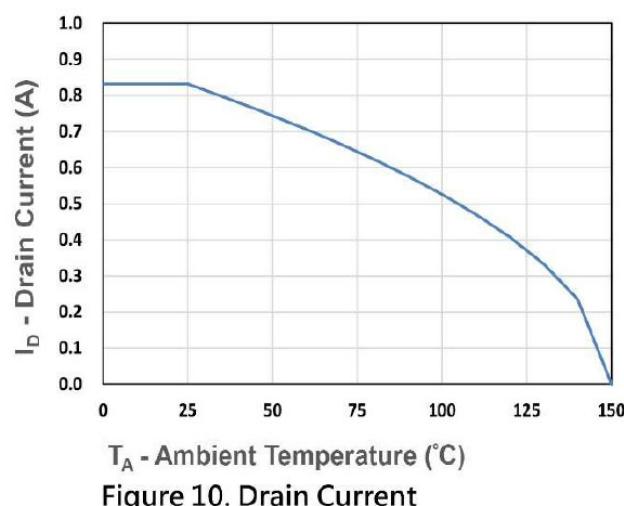
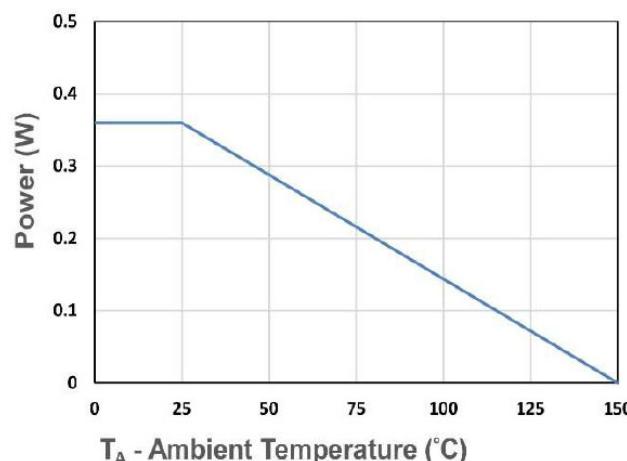
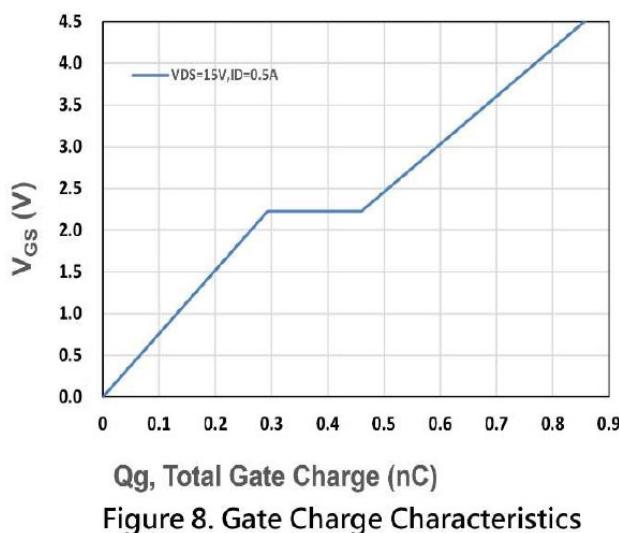
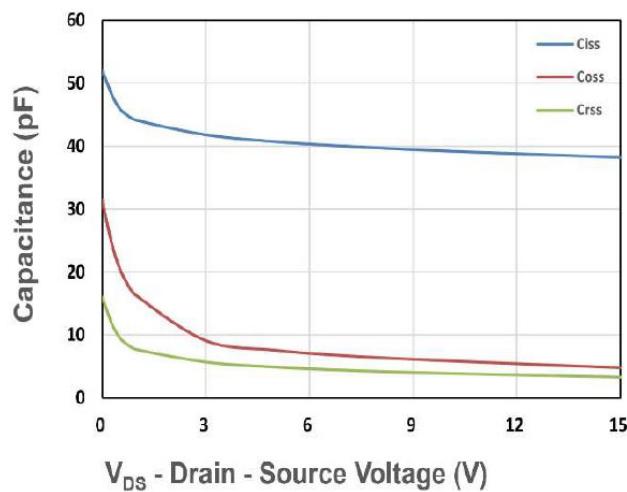
T_j , Junction Temperature(°C)

Figure 5. Drain-Source On Resistance

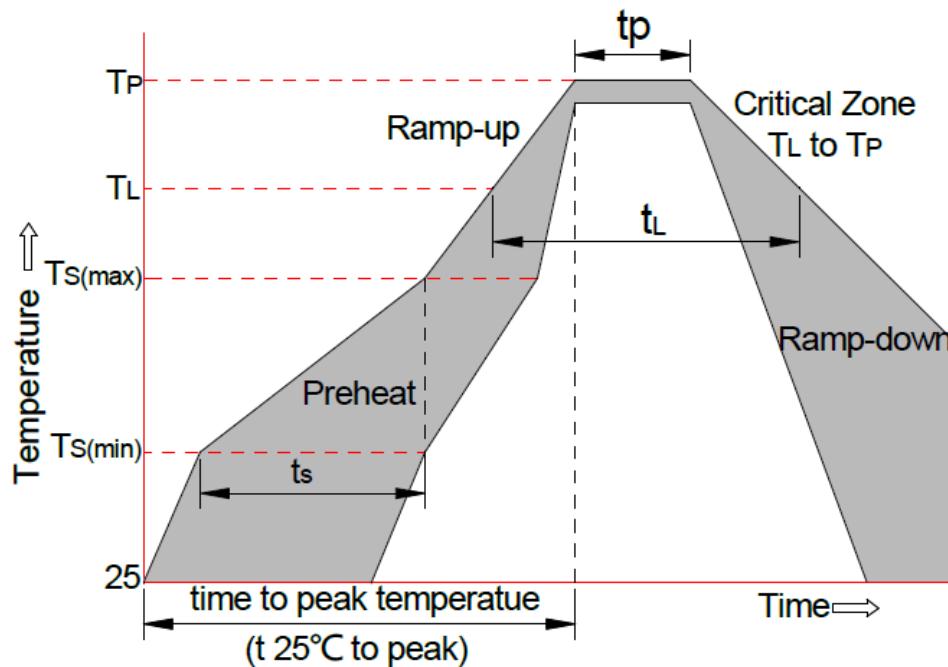


V_{SD}, Source-Drain Voltage(V)

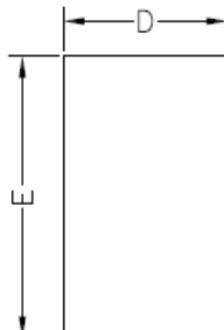
Figure 6. Source-Drain Diode Forward



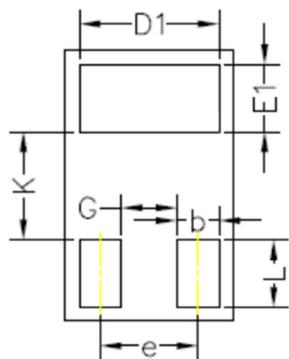
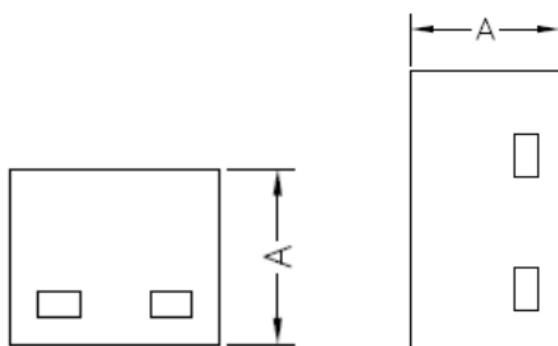
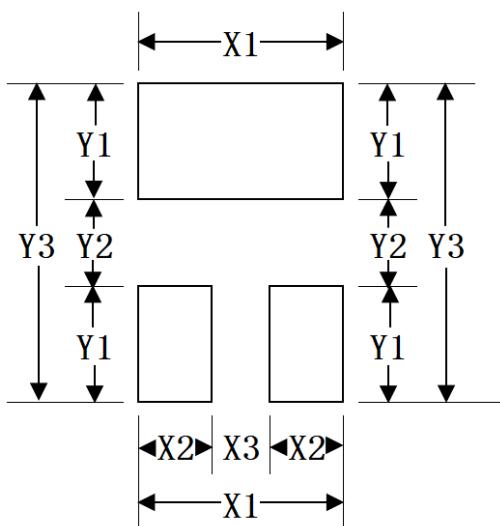
Soldering Parameters



| Reflow Conditions | | Pb-Free Assembly |
|---|--|------------------|
| Pre-heat | -Temperature Min (Ts (min)) | +150°C |
| | -Temperature Max (Ts (max)) | +200°C |
| | -Time (Min to Max) (ts) | 60-180 secs |
| Average ramp up rate(Liquid us Temp (T _L) to peak) | | 3°C/sec. Max |
| T _{S (max)} to T _L -Ramp-up Rate | | 3°C/sec. Max |
| Reflow | -Temperature (T _L) (Liquid us) | +217°C |
| | -Temperature (t _L) | 60-150 secs |
| Peak Temp (T _p) | | +260(+0/-5)°C |
| Time within 5°C of actual Peak Temp (t _p) | | 30 secs. Max |
| Ramp-down Rate | | 6 °C/secs. Max |
| Time 25°C to Peak Temp (T _P) | | 8 min. Max |
| Do not exceed | | +260°C |

DFN1006-3L Package Outline Drawing

TOP VIEW

| SYM | DIMENSIONS | | | | | |
|-----|-------------|------|------|--------|--------|--------|
| | MILLIMETERS | | | INCHES | | |
| | Min | Typ | Max | Min | Typ | Max |
| A | 0.50 | 0.55 | 0.60 | 0.0197 | - - | 0.0236 |
| D | 0.55 | 0.60 | 0.65 | 0.0217 | 0.0236 | 0.0256 |
| E | 0.95 | 1.00 | 1.05 | 0.0374 | 0.0394 | 0.0413 |
| D1 | 0.45 | 0.50 | 0.55 | 0.0177 | 0.0197 | 0.0217 |
| E1 | 0.20 | 0.25 | 0.30 | 0.0079 | 0.0098 | 0.0118 |
| e | 0.35 BSC | | | | | |
| L | 0.20 | 0.25 | 0.30 | 0.0079 | 0.0098 | 0.0118 |
| b | 0.10 | 0.15 | 0.20 | 0.0039 | 0.0059 | 0.0079 |
| G | 0.15 | 0.20 | 0.25 | 0.0059 | 0.0079 | 0.0098 |
| K | 0.35 | 0.40 | 0.45 | 0.0138 | 0.0157 | 0.0177 |


BOTTOM VIEW

SIDE VIEW
SIDE VIEW
Suggested Land Pattern


| SYM | DIMENSIONS | |
|-----|-------------|--------|
| | MILLIMETERS | INCHES |
| X1 | 0.70 | 0.028 |
| X2 | 0.25 | 0.010 |
| X3 | 0.20 | 0.008 |
| Y1 | 0.40 | 0.016 |
| Y2 | 0.30 | 0.012 |
| Y3 | 1.10 | 0.043 |

Note:

The land pattern is for reference purposes only.

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